

# Isolated High Current IGBT Gate Driver

Product Preview

# NCD57100, NCD57101, NCV57100, NCV57101

NCx5710y is a high–current single channel IGBT driver with internal galvanic isolation, designed for high system efficiency and reliability in high power applications. Its features include complementary inputs, open drain FAULT and READY outputs, active MILLER CLAMP, accurate UVLOs, DESAT protection and DESAT diagnostic function, soft turn–off at DESAT, Disable output function and separate high and low (OUTH and OUTL) driver outputs (NCx57100) for system design convenience. NCx5710y accommodates both 5 V and 3.3 V signals on the input side and wide bias voltage range on the driver side including negative voltage capability. NCx5710y provides > 5 kVrms (UL1577 rating) galvanic isolation and > 1200  $V_{\rm IORM}$  (working voltage) capabilities. NCx5710y is available in the wide–body SOIC–16 package with guaranteed 8 mm creepage distance between input and output to fulfill reinforced safety insulation requirements.

#### **Features**

- High Current Peak Output (±7 A)
- Low Output Impedance for Enhanced IGBT Driving
- Short Propagation Delays with Accurate Matching
- Active Miller Clamp to Prevent Spurious Gate Turn-on
- DESAT Protection with Programmable Delay
- DESAT Diagnostic Function
- Output Disable Function
- Negative Voltage (Down to -8 V) Capability for DESAT
- Soft Turn Off During IGBT Short Circuit
- IGBT Gate Clamping During Short Circuit
- Tight UVLO Thresholds for Bias Flexibility
- Wide Bias Voltage Range including Negative VEE2
- 3.3 V to 5 V Input Supply Voltage
- Designed for AEC-Q100 Certification
- 5000 V Galvanic Isolation (to meet UL1577 Requirements)
- 1200 V Working Voltage (per VDE0884-11 Requirements)
- High Transient Immunity
- High Electromagnetic Immunity
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant

#### **Typical Applications**

- Automotive Applications
- Solar Inverters

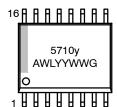
Motor Control

- Welding
- Industrial Power Supplies
- Uninterruptible Power Supplies (UPS)

This document contains information on a product under development. **onsemi** reserves the right to change or discontinue this product without notice.



#### **MARKING DIAGRAM**



5710y = Specific Device Code

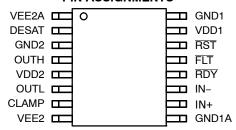
(y = 0 or 1)

A = Assembly Location

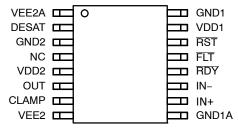
WL = Wafer Lot YY = Year WW = Work Week

G = Pb-Free Package

#### **PIN ASSIGNMENTS**



NCx57100 (x = D or V)



NCx57101 (x = D or V)

### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 9  $\,$  of this data sheet.

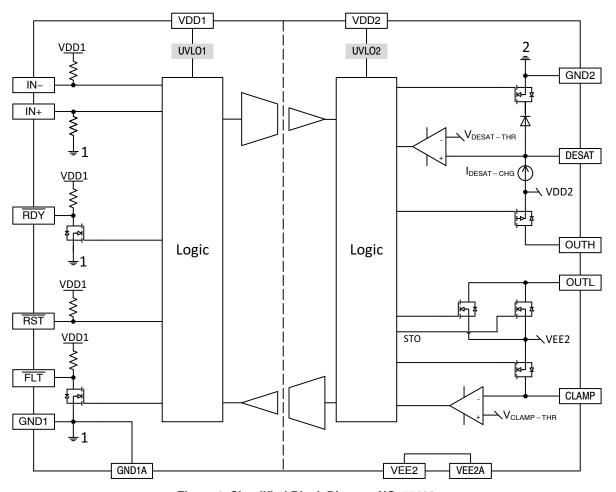


Figure 1. Simplified Block Diagram NCx57100

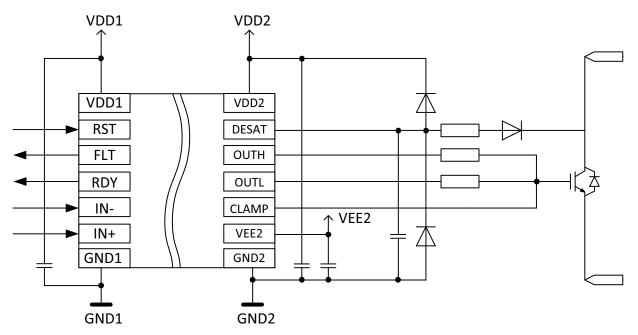


Figure 2. Simplified Application Schematics NCx57100

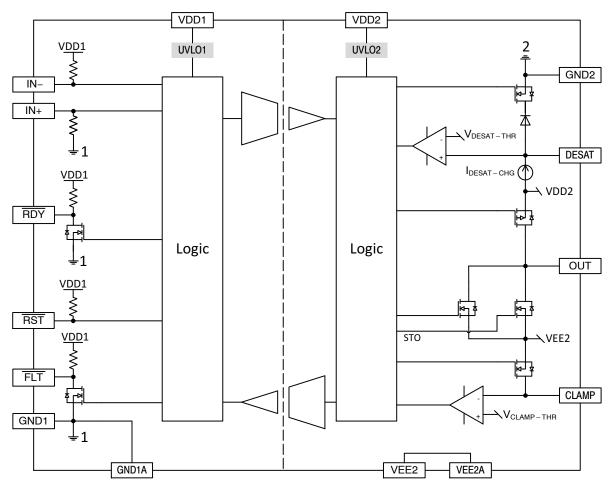


Figure 3. Simplified Block Diagram NCx57101

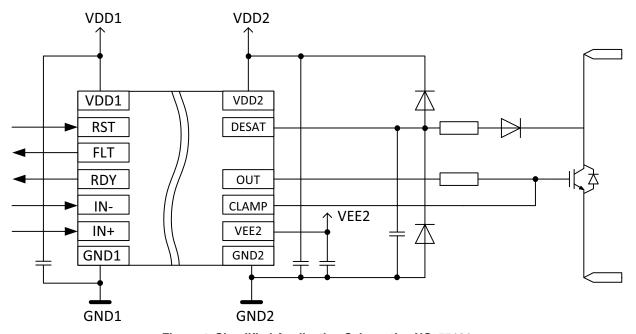


Figure 4. Simplified Application Schematics NCx57101

### **PIN DESCRIPTION**

Pin Name	No.	I/O	Description
V <sub>EE2A</sub>	1 8	Power	Output side negative power supply. A good quality bypassing capacitor is required from these pins to GND2 and should be placed close to the pins for best results. Connect it to GND2 for unipolar supply application. Thermal cooling polygons should be applied to this pins for better cooling of the case.
DESAT	2	I/O	Input for detecting the desaturation of IGBT due to a short circuit condition. An internal constant current source I <sub>DESAT-CHG</sub> charging an external capacitor connected to this pin allows a programmable blanking delay every ON cycle before DESAT fault is processed, thus preventing false triggering. When the DESAT voltage goes up and reaches V <sub>DESAT-THR</sub> , the output is driven low. Further, the /FLT output is activated, please refer to Figure 7 on page 11.
			A 5 μs mute time applies to IN+ and IN- once DESAT occurs.
GND2	3	Power	Output side gate drive reference connecting to IGBT emitter or FET source.
OUTH (NCx57100)	4	0	Driver high output that provides the appropriate drive voltage and source current to the IGBT/FET gate.
N/C (NCx57101)			Not Connected
$V_{\mathrm{DD2}}$	5	Power	Output side positive power supply. The operating range for this pin is from UVLO2 to its maximum allowed value. A good quality bypassing capacitor is required from this pin to GND2 and should be placed close to the pins for best results.
OUTL (NCx57100) OUT (NCx57101)	6	0	Driver low output that provides the appropriate drive voltage and sink current to the IGBT/FET gate.
CLAMP	7	I/O	Provides clamping for the IGBT/FET gate during the off period to protect it from parasitic turn–on. Its internal NFET is turned on when the voltage of this pin falls below $V_{\text{EE2}} + V_{\text{CLAMP-THR}}$ . It is to be tied directly to IGBT/FET gate with minimum trace length for best results.
GND1A	9	Power	Input side ground reference.
GND1	16		
IN+	10	I	Non inverted gate driver input. It is internally clamped to $V_{DD1}$ and has a pull–down resistor of 50 k $\Omega$ to ensure that output is low in the absence of an input signal. A minimum positive or negative going pulse–width is required at IN+ before OUTx respond.
IN-	11	I	Inverted gate driver input. It is internally clamped to $V_{DD1}$ and has a pull-up resistor of 50 k $\Omega$ to ensure that output is low in the absence of an input signal. A minimum positive or negative going pulse-width is required at IN- before OUTx respond.
RDY	12	0	Power good indication output, active high when $V_{DD1}$ and $V_{DD2}$ are both good. There is an internal 50 k $\Omega$ pull-up resistor connected to this pin. Multiple of them from different drivers can be "OR"ed together. OUTx remain low when RDY is low. Short time delays may apply. See Figure 6 on page 10 for details.
/FLT	13	0	Fault output (active low) that allows communication to the main controller that the driver has encountered a desaturation condition and has deactivated the output. There is an internal 50 k $\Omega$ pull–up resistor connected to this pin. Multiple of them from different drivers can be "OR"ed together.
/RST	14	I	<ol> <li>RESET: Reset input with an internal 50 kΩ pull-up resistor, active low to reset fault latch.</li> <li>DISABLE: Active low to disable output function</li> <li>DSCHK: Activation of DESAT comparator check function. The DSCHK is activated after input of 15 pulses with 200 ns Low pulse width and 10 μs High pulse width (see Page 17)</li> </ol>
V <sub>DD1</sub>	15	Power	Input side power supply (3.3 V to 5 V).

### **SAFETY AND INSULATION RATINGS**

Symbol	Parameter	Value	Unit			
	Installation Classifications per DIN VDE 0110/1.89	I – IV				
	Table 1 Rated Mains Voltage < 300 V <sub>RMS</sub>					
		< 450 V <sub>RMS</sub>	I – IV			
		< 600 V <sub>RMS</sub>	I – IV			
		< 1000 V <sub>RMS</sub>	I – III			
CTI	Comparative Tracking Index (DIN IEC 112/VDE 0303 Part 1)		600			
	Climatic Classification		40/125/21			
	Polution Degree (DIN VDE 0110/1.89)	2				
$V_{PR}$	Input–to–Output Test Voltage, Method B, $V_{IORM} \times 1.875 = V_{PR}$ , 100% Product tm = 1 s, Partial Discharge < 5 pC	2250	$V_{pk}$			
$V_{IORM}$	Maximum Repetitive Peak Voltage	1200	$V_{pk}$			
$V_{IOWM}$	Maximum Working Voltage		870	V <sub>RMS</sub>		
$V_{IOTM}$	Highest Allowable Over Voltage		8400	$V_{pk}$		
E <sub>CR</sub>	External Creepage		8.0	mm		
E <sub>CL</sub>	External Clearance		8.0	mm		
DTI	Insulation Thickness	17.3	um			
T <sub>Case</sub>	Safety Limit Values – Maximum Values in Failure; Case Temperature	150	°C			
P <sub>S,INPUT</sub>	Safety Limit Values – Maximum Values in Failure; Input Power	36	mW			
P <sub>S,OUTPUT</sub>	Safety Limit Values – Maximum Values in Failure; Output Power	1364	mW			
R <sub>IO</sub>	Insulation Resistance at TS, V <sub>IO</sub> = 500 V	10 <sup>9</sup>	Ω			

### ABSOLUTE MAXIMUM RATINGS (Over operating free-air temperature range unless otherwise noted) (Note 1)

Symbol	Parameter	Minimum	Maximum	Unit
V <sub>DD1</sub> -GND1	Supply voltage, input side	-0.3	6	V
V <sub>DD2</sub> -GND2	Positive Power Supply, output side	-0.3	32	V
V <sub>EE2</sub> -GND2	Negative Power Supply, output side	-18	-2	V
V <sub>DD2</sub> -V <sub>EE2</sub> (V <sub>MAX2</sub> )	Differential Power Supply, output side	-0.3	32	V
V <sub>OUTH</sub>	Positive gate-driver output voltage	V <sub>EE2</sub> - 0.3	V <sub>DD2</sub> + 0.3	V
V <sub>OUTL</sub>	Negative gate-driver output voltage	V <sub>EE2</sub> - 0.3	V <sub>DD2</sub> + 0.3	V
I <sub>PK</sub> -SRC	Gate-driver output sourcing current (maximum pulse width = 10 $\mu$ s, maximum duty cycle = 0.2%, $V_{DD2}$ = +15 V, $V_{EE2}$ = -8 V)	-	7.8	Α
I <sub>PK-SNK</sub>	Gate-driver output sinking current (maximum pulse width = 10 $\mu$ s, maximum duty cycle = 0.2%, $V_{DD2}$ = +15 V, $V_{EE2}$ = -8 V)	-	7.1	Α
I <sub>PK-CLAMP</sub>	Clamp sinking current (maximum pulse width = 10 $\mu$ s, maximum duty cycle = 0.2%, $V_{CLAMP}$ = 2.5 V)		2.5	Α
t <sub>CLP</sub>	Maximum Short Circuit Clamping Time (I <sub>OUTH_CLAMP</sub> = 500 mA)	_	10	μs
V <sub>LIM</sub> -GND1	Voltage at IN+, IN-, /RST, /FLT, RDY	-0.3	V <sub>DD1</sub> + 0.3	V
I <sub>LIM</sub> -GND1	Output current of /FLT, RDY	-	10	mA
V <sub>DESAT</sub> -GND2	Desat Voltage (Note 2)	-9	V <sub>DD2</sub> + 0.3	V
V <sub>CLAMP</sub> -V <sub>EE2</sub>	Clamp Voltage	V <sub>EE2</sub> - 0.3	V <sub>DD2</sub> + 0.3	V
P <sub>D</sub>	Power Dissipation (Note 3)	-	1400	mW
T <sub>J(max)</sub>	Maximum Junction Temperature	-40	150	°C
T <sub>STG</sub>	Storage Temperature Range		150	°C
ESD <sub>HBM</sub>	ESD Capability, Human Body Model (Note 4)		±2	kV
ESD <sub>CDM</sub>	ESD Capability, Charged Device Model (Note 4)		±1.5	kV
MSL	Moisture Sensitivity Level		1	_
T <sub>SLD</sub>	Lead Temperature Soldering Reflow, Pb-Free Versions (Note 5)	-	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. Refer to ELECTRICAL CHĂRACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.
- The minimum value is verified by characterization with a single pulse of 1.5 mA for 300 μs.
- 3. The value is estimated for ambient temperature 25°C and junction temperature 150°C, 650 mm², 1 oz copper, 2 surface layers and 2 internal power plane layers. Power dissipation is affected by the PCB design and ambient temperature.

  4. This device series incorporates ESD protection and is tested by the following methods:
- - ESD Human Body Model tested per AEC-Q100-002 (EIA/JESD22-A114)
  - ESD Charged Device Model tested per AEC-Q100-011 (EIA/JESD22-C101)
- Latchup Current Maximum Rating: ≤100 mA per JEDEC standard: JESD78, 25°C
- 5. For information, please refer to our Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### THERMAL CHARACTERISTICS

Symbol	Parameter	Conditions	Value	Unit
$R_{\theta JA}$	Thermal Resistance, Junction-to-Air	100 mm <sup>2</sup> , 2 oz Copper, 1 Surface Layer	95	°C/W
		100 mm <sup>2</sup> , 2 oz Copper, 2 Surface Layers and 2 Internal Power Plane Layers	71	

### **RECOMMENDED OPERATING RANGES (Note 6)**

Symbol	Parameter	Min	Max	Unit
V <sub>DD1</sub> -GND1	Supply voltage, input side	UVLO1	5.5	V
V <sub>DD2</sub> -GND2	Positive Power Supply, output side	UVLO2	30	V
V <sub>EE2</sub> -GND2	Negative Power Supply, output side	-16	-3	V
V <sub>DD2</sub> -V <sub>EE2</sub> (V <sub>MAX2</sub> )	Differential Power Supply, output side	0	30	V
V <sub>IL</sub>	Low level input voltage at IN+, IN-, /RST	0	0.3 X V <sub>DD1</sub>	V
V <sub>IH</sub>	High level input voltage at IN+, IN-, /RST	0.7 X V <sub>DD1</sub>	$V_{DD1}$	V
dV <sub>ISO</sub> /dt	Common Mode Transient Immunity	150	_	kV/μs
T <sub>A</sub>	Ambient Temperature	-40	125	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

6. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.

#### **ISOLATION CHARACTERISTICS**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>ISO,</sub> input-output	Input-Output Isolation Voltage	$T_A$ = 25°C, Relative Humidity < 50%, t = 1.0 minute, $I_{I-O}$ <30 $\mu A$ , 50 Hz (See Note 7, 8, 9)	5000	-	-	V <sub>RMS</sub>
R <sub>ISO</sub>	Isolation Resistance	V <sub>I-O</sub> = 500 V (See Note 7)	-	10 <sup>11</sup>	-	Ohm

- 7. Device is considered a two-terminal device: pins 1 to 8 are shorted together and pins 9 to 16 are shorted together.
- 8. 5,000  $V_{RMS}$  for 1-minute duration is equivalent to 6,000  $V_{RMS}$  for 1-second duration.

**ELECTRICAL CHARACTERISTICS** ( $V_{DD1} = 5 \text{ V}$ ,  $V_{DD2} = 15 \text{ V}$ ,  $V_{EE2} = -8 \text{ V}$ . For typical values  $T_A = 25^{\circ}\text{C}$ , for min/max values,  $T_A$  is the operating ambient temperature range that applies, unless otherwise noted)

Symbol	Parameter	Min	Тур	Max	Unit	
OLTAGE SUPPLY			•	•		
V <sub>UVLO1-OUT-ON</sub>	UVLO1 Output Enabled		-	-	3	V
V <sub>UVLO1-OUT-OFF</sub>	UVLO1 Output Disabled		2.4	-	-	V
V <sub>UVLO1-HYST</sub>	UVLO1 Hysteresis		0.1	0.125	-	V
V <sub>UVLO2-OUT-ON</sub>	UVLO2 Output Enabled		12.7	13	13.3	V
V <sub>UVLO2-OUT-OFF</sub>	UVLO2 Output Disabled		11.7	12	12.3	٧
V <sub>UVLO2-HYST</sub>	UVLO2 Hysteresis		0.8	1		٧
I <sub>DD1-0</sub>	I <sub>DD1-0</sub> Input Supply Quiescent Current Output Low IN+ = Low, IN- = Low RDY = High, /FLT = High		-	1	2	mA
I <sub>DD1-100</sub>	Input Supply Quiescent Current Output High	IN+ = High, IN- = Low RDY = High, /FLT = High	-	4.8	6	mA
I <sub>DD2-0</sub>	Output Positive Supply Quiescent Current, Output Low	IN+ = Low, IN- = Low RDY = High, /FLT = High, no load	-	3.3	4	mA
I <sub>DD2-100</sub>	Output Positive Supply Quiescent Current, Output High	IN+ = High, IN- = Low RDY = High, /FLT = High, no load	_	3.6	4	mA
I <sub>EE2-0</sub>	I <sub>EE2-0</sub> Output Negative Supply Quiescent Current, Output Low		-	0.2	2	mA
I <sub>EE2-100</sub>	Output Negative Supply Quiescent Current, Output High	IN+ = High, IN- = Low, no load	-	0.4	2	mA
OGIC INPUT AND	ОИТРИТ	•	•	•	•	.=
V <sub>IL</sub>	IN+, IN-, /RST Low Input Voltage		-	_	0.3 x V <sub>DD1</sub>	٧

The input-output isolation voltage is a dielectric voltage rating per UL1577. It should not be regarded as an input-output continuous voltage
rating. For the continuous working voltage rating, refer to equipment-level safety specification or DIN VDE V 0884-11 Safety and Insulation
Ratings Table.

**ELECTRICAL CHARACTERISTICS** ( $V_{DD1} = 5 \text{ V}$ ,  $V_{DD2} = 15 \text{ V}$ ,  $V_{EE2} = -8 \text{ V}$ . For typical values  $T_A = 25^{\circ}\text{C}$ , for min/max values,  $T_A$  is the operating ambient temperature range that applies, unless otherwise noted) (continued)

Symbol	Parameter Test Condition		Min	Тур	Max	Unit
LOGIC INPUT AND	OUTPUT					
V <sub>IH</sub>	IN+, IN-, /RST High Input Voltage		0.7 x V <sub>DD1</sub>	_	-	٧
V <sub>IN-HYST</sub>	Input Hysteresis Voltage		-	0.15 x V <sub>DD1</sub>	-	٧
I <sub>IN-L</sub> , I <sub>RST-L</sub>	IN-, /RST Input Current (50 kΩ pull-up resistor)	V <sub>IN-</sub> , V <sub>RST</sub> = 0 V	-	-100	-	μΑ
I <sub>IN+H</sub>	IN+ Input Current (50 kΩ pull-down resistor)	V <sub>IN+</sub> = 5 V	-	100	-	μΑ
I <sub>RDY-L</sub> , I <sub>FLT-L</sub>	RDY, /FLT Pull-up Current (50 kΩ pull-up resistor)	V <sub>RDY</sub> , V <sub>FLT</sub> = Low	-	100	-	μΑ
$V_{RDY-L}, V_{FLT-L}$	RDY, /FLT Low Level Output Voltage	I <sub>RDY</sub> , I <sub>FLT</sub> = 5 mA	-	_	0.3	V
t <sub>MIN1</sub>	Input Pulse Width of IN+, IN- for No Response at Output		-	-	10	ns
t <sub>MIN2</sub>	Input Pulse Width of IN+, IN- for Guaranteed Response at Output		500	_	-	ns
t <sub>RST-MIN</sub>	Pulse Width of /RST for Resetting /FLT		800	_	-	ns
t <sub>UV2R</sub> , t <sub>UV2F</sub>	UVLO2 Filter Time		-	1	-	μs
DRIVER OUTPUT						
V <sub>OUTL1</sub>	Output Low State	I <sub>SINK</sub> = 200 mA	-	0.1	0.2	V
V <sub>OUTL2</sub>	(V <sub>OUTL</sub> – V <sub>EE2</sub> )	I <sub>SINK</sub> = 1.0 A, T <sub>A</sub> = 25°C	-	0.5	0.8	
V <sub>OUTH1</sub>	Output High State	I <sub>SRC</sub> = 200 mA	-	0.3	0.5	V
V <sub>OUTH2</sub>	(V <sub>DD2</sub> – V <sub>OUTH</sub> )	I <sub>SRC</sub> = 1.0 A, T <sub>A</sub> = 25°C	-	0.8	1	1
I <sub>PK-SNK1</sub>	Peak Driver Current, Sink (Note 10)		-	7.1	_	Α
I <sub>PK-SRC1</sub>	Peak Driver Current, Source (Note 10)		-	7.8	-	Α
I <sub>PK-SNK-STO</sub>	Soft Turn Off Sinking Current	$V_{EE2} = -8 \text{ V}, T_A = 25^{\circ}\text{C},$ $C_G = 100 \text{ nF}, R_G = 0 \Omega$	-	200	-	mA
MILLER CLAMP			•			•
V <sub>CLAMP</sub>	Clamp Voltage	I <sub>CLAMP</sub> = 2.5 A, T <sub>A</sub> = 25°C	_	1.3	1.7	V
	(V <sub>CLAMP</sub> – V <sub>EE2</sub> )	I <sub>CLAMP</sub> = 2.5 A, T <sub>A</sub> = -40°C to 125°C	-	-	2.7	1
V <sub>CLAMP-THR</sub>	Clamp Activation Threshold (V <sub>CLAMP</sub> – V <sub>EE2</sub> )		1.5	2	2.5	V
GBT SHORT CIRC	UIT CLAMPING		•			•
V <sub>CLAMP-OUTH</sub>	Clamping Voltage, Sourcing (V <sub>OUTH</sub> - V <sub>DD2</sub> )	I <sub>CLAMP-OUTH</sub> = 500 mA (pulse test, t <sub>CLPmax</sub> = 10 μs)	_	0.9	1	V
DESAT PROTECTION	ON		•			•
V <sub>DESAT-THR</sub>	DESAT Threshold Voltage		8.5	9	9.5	V
V <sub>DESAT-NEG</sub>	DESAT Negative Voltage	I <sub>DESAT</sub> = 1.5 mA	-8	-	_	V
I <sub>DESAT-CHG</sub>	Blanking Charge Current	V <sub>DESAT</sub> = 7 V	0.45	0.5	0.6	mA
I <sub>DESAT-DIS</sub>	Blanking Discharge Current		-	50	-	mA
DESAT CHECK FU	NCTIONS		•			•
t <sub>RST-ACT1</sub>	Negative Input Pulse Width to activate DSCHK function	(see Figure 9)	_	200	-	ns
<sup>t</sup> rst-act	Input Pulse Width to activate DSCHK function	15 LOW pulses t <sub>RST-ACT</sub> on /RST pin (see Figure 9)	8	_	10	μs

**ELECTRICAL CHARACTERISTICS** ( $V_{DD1} = 5 \text{ V}$ ,  $V_{DD2} = 15 \text{ V}$ ,  $V_{EE2} = -8 \text{ V}$ . For typical values  $T_A = 25^{\circ}\text{C}$ , for min/max values,  $T_A$  is the operating ambient temperature range that applies, unless otherwise noted) (continued)

Symbol	Parameter	Test Condition	Min	Тур	Max	Unit
DISABLE OUTPU	Т		•	•	_	
t <sub>RST-DIS</sub>	Output disable function	Negative pulse on /RST pin to disable output	90	_	-	ns
DYNAMIC CHARA	ACTERISTICS				•	•
t <sub>PD-ON</sub>	IN+, IN- to Output High Propagation Delay	C <sub>LOAD</sub> = 10 nF V <sub>IH</sub> to 10% of pulse width higher than t <sub>MIN2</sub> . OUTx and CLAMP pins are connected together	40	60	90	ns
t <sub>PD-OFF</sub>	IN+, IN- to Output Low Propagation Delay	C <sub>LOAD</sub> = 10 nF V <sub>IL</sub> to 90% of pulse width higher than t <sub>MIN2</sub> . OUTx and CLAMP pins are connected together	40	66	90	ns
<sup>†</sup> DISTORT	Propagation Delay Distortion (= t <sub>PD-ON</sub> - t <sub>PD-OFF</sub> )	$T_A = 25$ °C, pulse width higher than $t_{MIN2}$	-15	-6	15	ns
		$T_A = -40$ °C to 125°C, pulse width higher than $t_{MIN2}$	-25	-	25	
t <sub>DISTORT_TOT</sub>	Prop Delay Distortion between Parts	PW > 150 ns	-30	0	30	ns
t <sub>RISE</sub>	Rise Time (see Fig. 5) (Note 10)	C <sub>LOAD</sub> = 1 nF, 10% to 90% of Output Change	_	10	-	ns
t <sub>FALL</sub>	Fall Time (see Fig. 5) (Note 10)	C <sub>LOAD</sub> = 1 nF, 90% to 10% of Output Change	-	15	-	ns
t <sub>LEB</sub>	DESAT Leading Edge Blanking Time (See Fig. 7)		_	400	-	ns
<sup>t</sup> FILTER	DESAT Threshold Filtering Time (see Fig. 7)		_	320	-	ns
t <sub>FLT</sub>	Delay after t <sub>FILTER</sub> to /FLT		-	450	-	ns
t <sub>MUTE</sub>	DESAT Mute time after t <sub>FILTER</sub>		_	5	-	μs
t <sub>RST</sub>	/RST Rise to /FLT Rise Delay		-	23	100	ns
t <sub>RDY10</sub>	RDY High to Output High Delays		_	55	-	ns
t <sub>RDY20</sub>	(see Fig. 6)					
t <sub>RDY1F</sub> t <sub>RDY2F</sub>	V <sub>UVLOX-OUT-OFF</sub> to RDY Low Delays (see Fig. 6)		-	1 2.4	- -	μS

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

10. Values based on design and/or characterization.

#### **ORDERING INFORMATION**

Device	Qualification	Package Type	Shipping <sup>†</sup>
NCD57100DWR2G	NCD – Industry NCV – Automotive	SOIC-16 Wide Body	1,000 / Tape & Reel
NCV57100DWR2G	NCV - Automotive	(Pb-Free)	
NCD57101DWR2G			
NCV57101DWR2G			

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

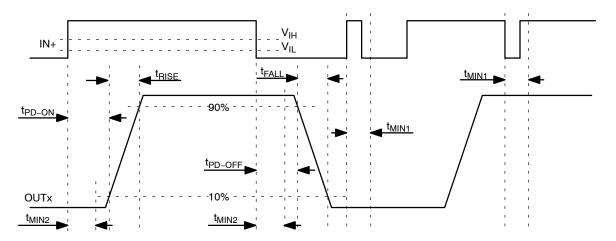


Figure 5. Propagation Delay, Rise and Fall Time

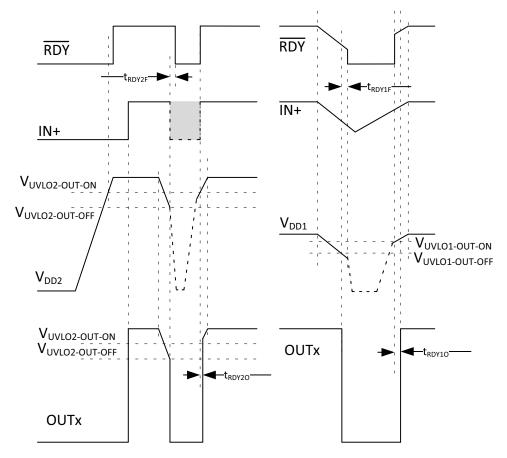


Figure 6. UVLO Waveform

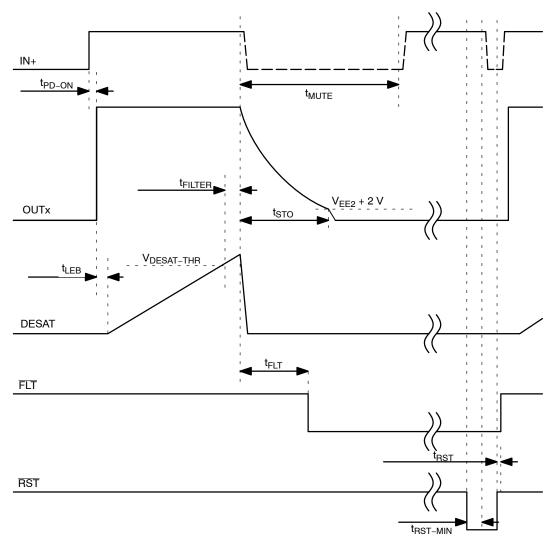
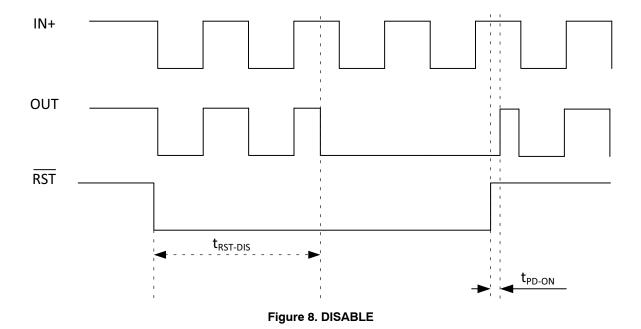
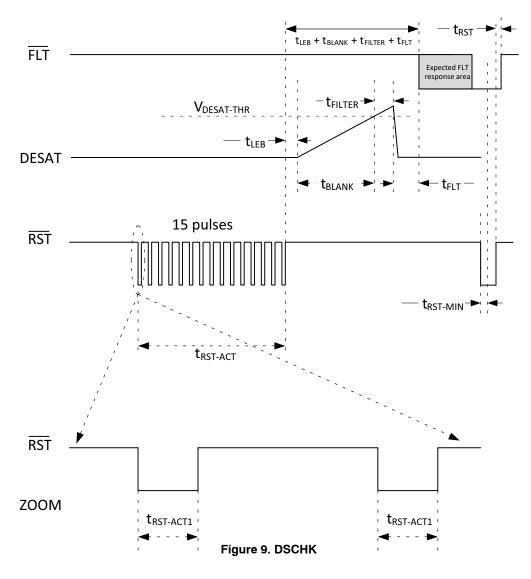


Figure 7. DESAT Response Waveform





### **TRUTH TABLE**

IN	UVLO1	UVLO2	DESAT*	OUT	/RST	/RDY	/FLT	Notes
L	Inactive	Inactive	L	L	Х	7	7	Initial condition after power up $V_{DD1}$ and $V_{DD2}$
7	Inactive	Inactive	L	7	Х	Н	Н	Initial condition – IN First Rising edge
Н	Inactive	Inactive	L	Н	Х	Н	Н	Normal Operation – Output High
L	Inactive	Inactive	L	L	Х	Н	Н	Normal Operation – Output Low
Х	Active	Inactive	Х	L	Х	L	L	UVLO1 Activated – RDY Low ( t <sub>RDY1F</sub> ), FLT Low, Output Low
Х	Inactive	Inactive	Х	Х	Х	Н	Н	UVLO1 Recovered – RDY High, FLT High
Х	Inactive	Active	Х	L	Х	L	Н	UVLO2 Activated – RDY Low ( t <sub>RDY2F</sub> ), Output Low
Х	Inactive	Inactive	Х	Х	Х	Н	Н	UVLO2 Recovered – RDY High, FLT High
Н	Inactive	Inactive	H (>t <sub>FILTER</sub> )	L	Х	Н	L	DESAT Activated – FLT Low (t <sub>FLT</sub> ), Output Low
Х	Inactive	Inactive	L	Х	⅓ (>t <sub>RST</sub> )	Н	7	FLT reset, DESAT conditions disappear, t <sub>RST</sub> pulse applied
7 7	Inactive	Inactive	L	L	L (>t <sub>RST-DIS</sub> )	Н	Н	Output DISABLED
L	Inactive	Inactive	Х	L	15x t <sub>RST-ACT1</sub>	Н	L	DESAT circuit check function activated

<sup>\*</sup> L = V<sub>DESAT</sub> < V<sub>DESAT-THR</sub>, H = V<sub>DESAT</sub> > V<sub>DESAT-THR</sub>

### **TYPICAL CHARACTERISTICS**

(Conditions for the following figures are the same as stated for ELECTRICAL CHARACTERISTICS Table unless otherwise noted.

Typical and/or average values are used.)

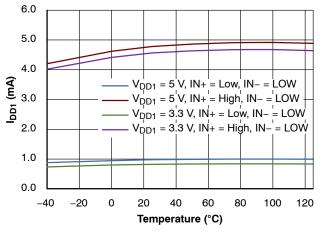


Figure 10. V<sub>DD1</sub> Supply Current

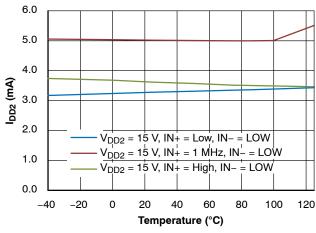


Figure 11. V<sub>DD2</sub> Supply Current

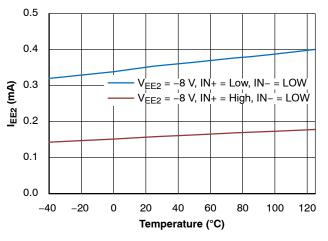


Figure 12. V<sub>EE2</sub> Supply Current

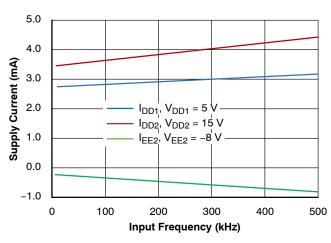


Figure 13. Supply Current vs Frequency

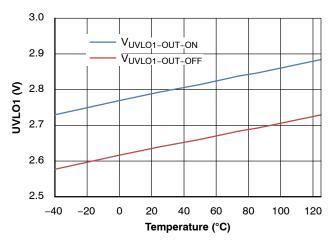


Figure 14. UVLO1 Threshold Voltage

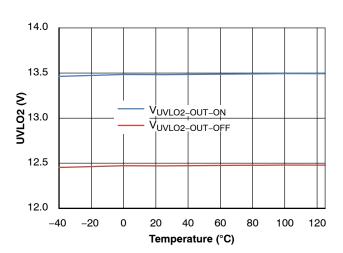
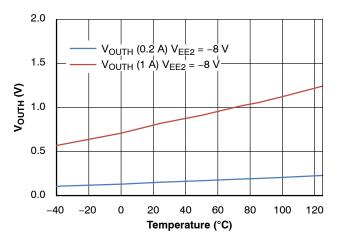


Figure 15. UVLO2 Threshold Voltage

### **TYPICAL CHARACTERISTICS**

(Conditions for the following figures are the same as stated for ELECTRICAL CHARACTERISTICS Table unless otherwise noted.

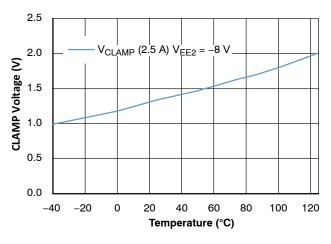
Typical and/or average values are used.) (continued)



2.0  $V_{OUTL}$  (0.2 A)  $V_{EE2} = -8 V$ 1.5  $V_{OUTL}$  (1 Å)  $V_{EE2} = -8 V_{OUTL}$ Voutl (V) 1.0 0.5 0.0 -40 -20 0 20 40 60 80 100 120 Temperature (°C)

Figure 16. Output Voltage Drop, Sourcing

Figure 17. Output Voltage Drop, Sinking



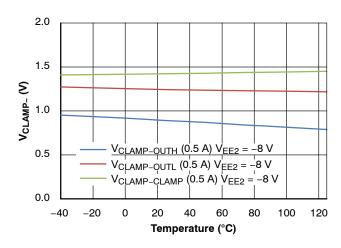
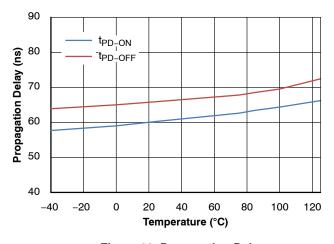


Figure 18. CLAMP Voltage Drop

Figure 19. IGBT Short Circuit Clamp Voltage Drop



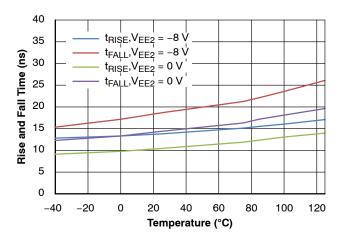


Figure 20. Propagation Delay

Figure 21. Rise and Fall Time

### **TYPICAL CHARACTERISTICS**

(Conditions for the following figures are the same as stated for ELECTRICAL CHARACTERISTICS Table unless otherwise noted.

Typical and/or average values are used.) (continued)

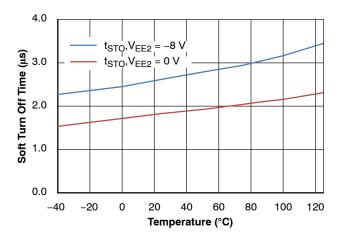


Figure 22. Soft Turn Off Time

### **FEATURE DESCRIPTIONS**

### **Under Voltage Lockout (UVLO)**

UVLO ensures correct switching of IGBT connected to the driver output.

- The IGBT is turned-off, if the supply V<sub>DD1</sub> drops below V<sub>UVLO1-OUT-OFF</sub> and the RDY pin output goes to low.
- The driver output does not start to react to the input signal on  $V_{IN}$  until the  $V_{DD1}$  rises above the  $V_{UVLO1-OUT-ON}$  again. If the supply  $V_{DD1}$  increase over  $V_{UVLO1-OUT-ON}$ , the RDY pin output goes to be open–drain and outputs continue to switch IGBT
- $\bullet$  The IGBT is turned–off, if the supply  $V_{DD2}$  drops below  $V_{UVLO2-OUT-OFF}$  and the RDY pin output goes to low.
- The driver output does not start to react to the input signal on V<sub>IN</sub> until the V<sub>DD2</sub> rises above the V<sub>UVLO2-OUT-ON</sub> again. If the supply V<sub>DD2</sub> increases over V<sub>UVLO2-OUT-ON</sub>, the RDY pin output goes to be open-drain and outputs continue to switch IGBT
- VEE2 is not monitored.

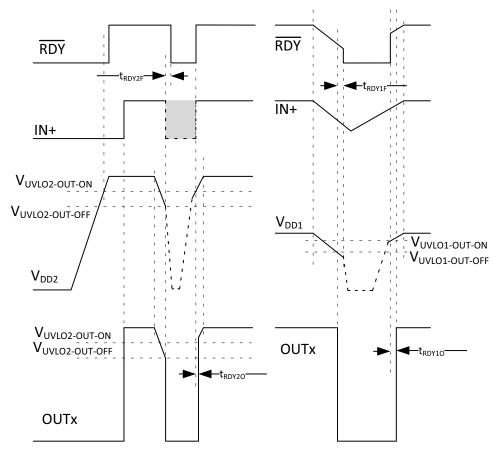


Figure 23. UVLO Diagram

### **Active Miller Clamp Protection (CLAMP)**

NCx5710y supports both bipolar and unipolar power supply with active Miller clamp.

For operation with bipolar supplies, the IGBT is turned off with a negative voltage through OUTL/OUT with respect to its emitter. This prevents the IGBT from unintentionally turning on because of current induced from its collector to its gate due to Miller effect. In this condition it is not necessary to connect CLAMP output of the gate driver to the IGBT gate, but connecting CLAMP output to the IGBT gate is also not an issue. Typical values for bipolar operation are  $V_{DD2} = 15 \ V$  and  $V_{EE2} = -8 \ V$  with respect to GND<sub>2</sub>.

For operation with unipolar supply, typically,  $V_{DD2} = 15 \text{ V}$  with respect to  $GND_2$ , and  $V_{EE2} = GND_2$ . In this case, the IGBT can turn on due to additional charge from IGBT Miller capacitance caused by a high voltage slew rate transition on the IGBT collector. To prevent IGBT to turn on, the CLAMP pin is connected directly to IGBT gate and Miller current is sunk through a low impedance CLAMP transistor. When the IGBT is turned–off and the gate voltage transitions below  $V_{CLAMP-THR}$ , the CLAMP current output is activated.

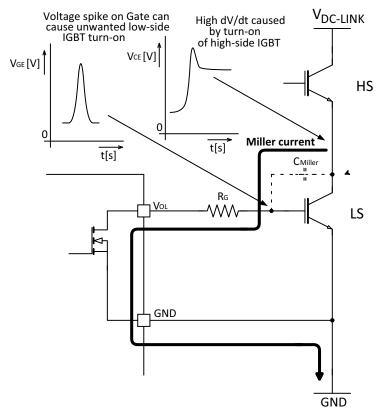


Figure 24. Current Path without Miler Clamp Protection

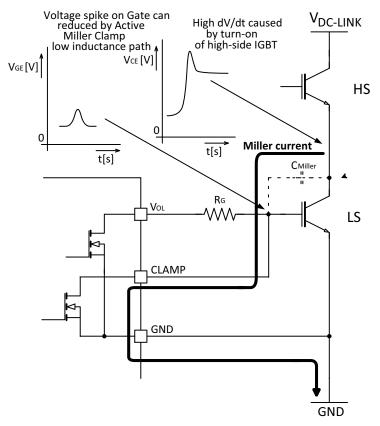


Figure 25. Current Path with Miler Clamp Protection

### Non-inverting and Inverting Input Pin (IN+, IN-)

NCx5710y has two possible input modes to control IGBT. Both inputs have defined minimum input pulse width to filter occasional glitches.

- Non-inverting input IN+ controls the driver output while inverting input IN- is set to LOW
- Inverting input IN- controls the driver output while non-inverting input IN+ is set to HIGH

Warning: When the application uses an independent or separate power supply for the control unit and the input side of the driver, all inputs should be protected by a serial resistor (In case of a power failure of the driver, the driver may be damaged due to overloading of the input protection circuits)

### **Desaturation Protection (DESAT)**

Desaturation protection ensures the protection of IGBT at short circuit. When the  $V_{\text{CE-SAT}}$  voltage goes up and reaches the set limit, the output is driven low and /FLT output is activated. Blanking time can be set by internal current source and an external capacitor. To avoid false DESAT triggering and minimize blanking time, fast switching diodes with low internal capacitance are recommended. All DESAT protective diodes internal capacitances build voltage divider with the blanking capacitor.

<u>Warning:</u> Both external protective diodes are recommended for the protection against voltage spikes caused by IGBT transients passing through parasitic capacitances.

### **DESAT Circuit Parameters Specification**

$$t_{BLANK} = C_{BLANK} \cdot \frac{V_{DESAT-THR}}{I_{DESAT-CHG}}$$

$$V_{DESAT-THR} > R_{S-DESAT} \cdot I_{DESAT-CHG} + V_{F HV diode} + V_{CESAT IGBT}$$

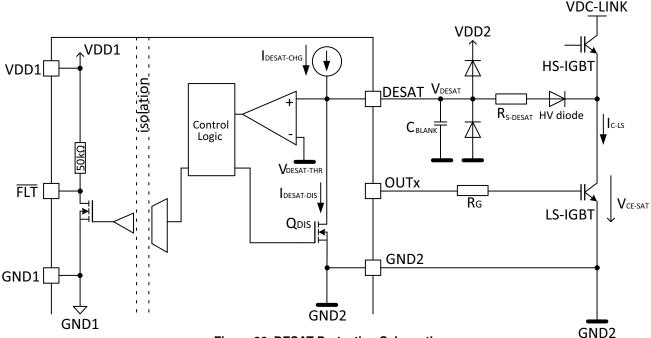


Figure 26. DESAT Protection Schematic

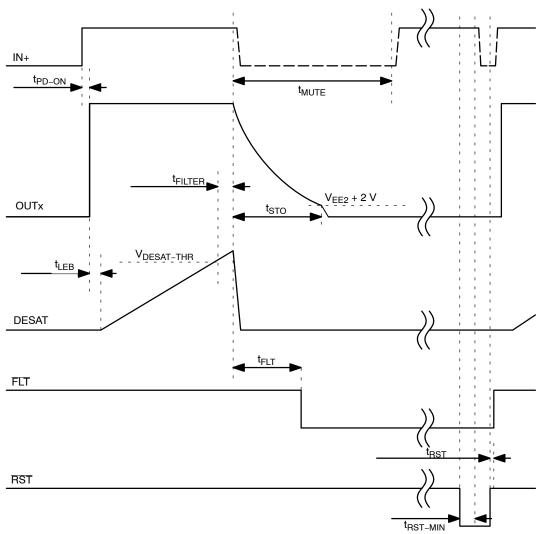


Figure 27. DESAT Switch Off Behavior

#### Fault Output Pin (FLT)

FLT open-drain output provides feedback to the controller about driver DESAT protection conditions. The open-drain FLT outputs of multiple NCx5710y devices can be wired together forming a single, common fault bus for interfacing directly to the microcontroller. FLT output has  $50 \text{ k}\Omega$  internal pull-up resistor to VDD1.

### Ready Output Pin (RDY)

RDY open-drain output provides feedback to the controller about driver UVLO protections conditions.

• If either side of device has insufficient supply (VDD1 or VDD2), the RDY pin output goes low; otherwise, RDY pin output is open drain.

The open-drain RDY outputs of multiple NCx5710y devices can be "OR"ed together.

### Reset Input Pin (RST)

Reset input pin is **ACTIVE LOW** and has internal pull-up resistor to VDD1. In normal condition the RST pin is connected to HIGH. To reset FAULT conditions or disable output pulses connect RST pin to LOW. To invoke DESAT Check (DSCHK) function apply pulse sequence (see Figure 9).

In applications that do not allow to control the reset, RST pin should be connected to IN+, the driver will be reset by each input pulse. In this case  $t_{MIN2}$  need to be longer than  $t_{RST}$ .

#### **RESET Input has Three Functions:**

- 1. Set back the FLT output
- 2. It can be used as Disable/shutdown output (independent of the input logic)
- 3. It can be used to test DESAT circuit functionality
- ◆ To set back FLT output ( If DESAT conditions are fulfilled and FLT output is activated), negative pulse of minimum length t<sub>RST</sub> needs to be applied to RST pin. (see Figure 5.)

- To disable output, negative pulse of minimum length t<sub>RST-DIS</sub> needs to be applied to RST pin. (see Figure X.)
- To activate DESAT check function apply 15 negative pulses of t<sub>RST-ACT1</sub> width and t<sub>RST-ACT</sub> pulse Length (See Figure X.)

Warning: When the application use an independent or separate power supply for the control unit ant the input side of the driver, all inputs should be protected by a serial resistor (In case of a power failure of the driver, the driver may be damaged due to overloading of the input protection circuits)

### Power Supply (VDD1, VDD2, VEE2)

NCx5710y is designed to support two different power supply configurations, bipolar or unipolar power supply. For reliable high output current delivery suitable external power capacitors are required. Parallel combination of 100 nF +  $4.7 \,\mu F$  ceramic capacitors is optimal for a wide range of applications using IGBT. For reliable driving of IGBT modules (containing several parallel IGBTs) a higher capacity is required (typically  $100 \, nF + 10 \, \mu F$ ). Capacitors should be as close as possible to the driver's power pins.

- In bipolar power supply the driver is typically supplied with a positive voltage of 15 V at VDD2 and negative voltage –5 V at VEE2 (Figure 28). Negative power supply prevents a dynamic turn on throughout the internal IGBT input capacitance.
- In Unipolar power supply the driver is typically supplied with a positive voltage of 15 V at VDD2. Dynamic turn on throughout the internal IGBT input capacitance could be prevented by Active Miler Clamp function. CLAMP output should be directly connected to IGBT gate (Figure 29).

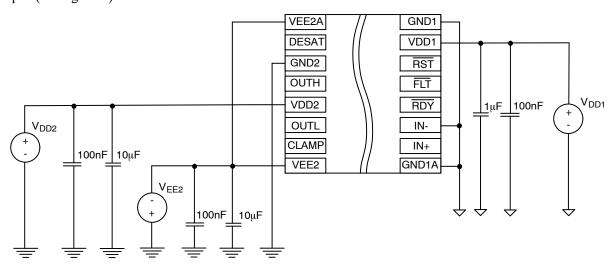


Figure 28. Bipolar Power Supply

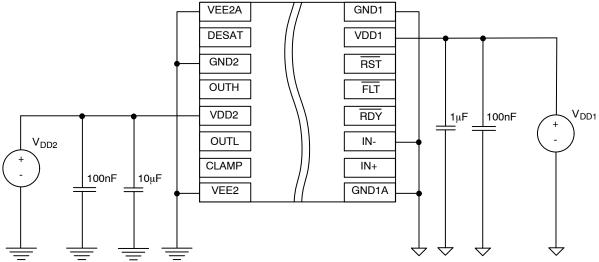


Figure 29. Unipolar Power Supply

### **Common Mode Transient Immunity (CMTI)**

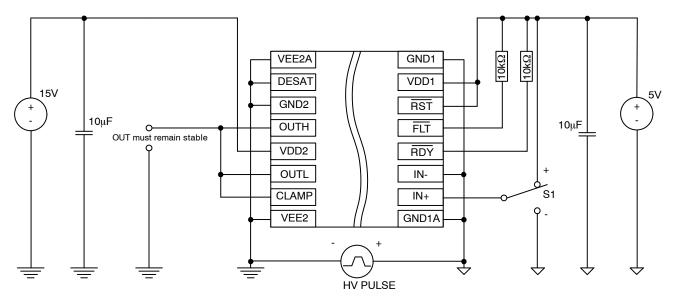


Figure 30. Common-Mode Transient Immunity Test Circuit

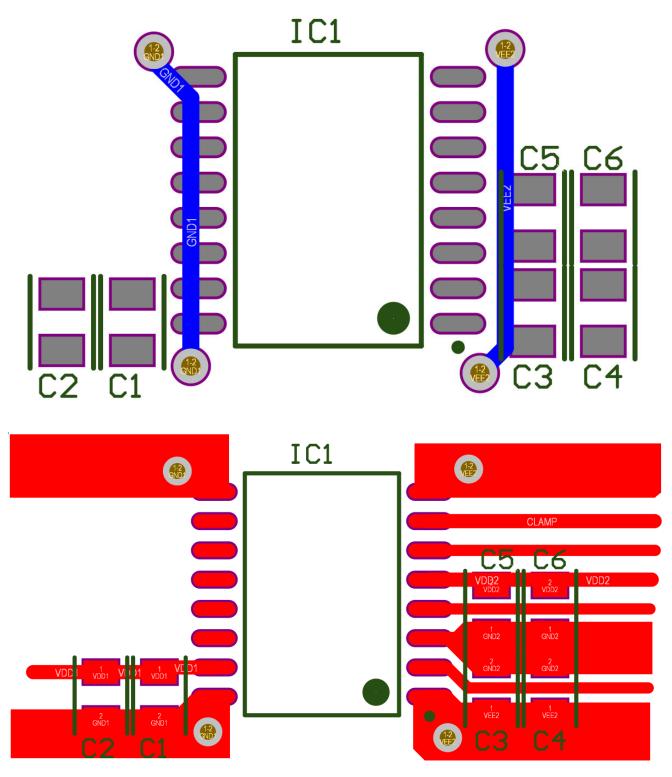


Figure 31. Recommended Basic Bipolar Power Supply PCB Design

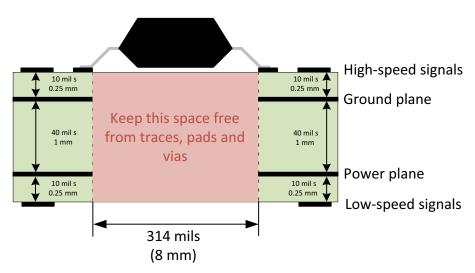
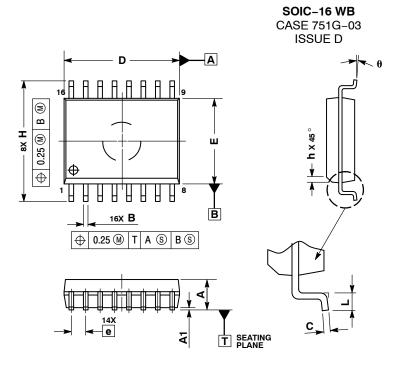


Figure 32. Recommended Layer Stack

#### PACKAGE DIMENSIONS

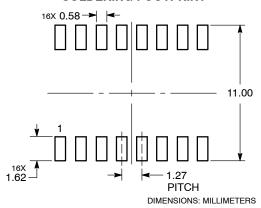


#### NOTES:

- DIMENSIONS ARE IN MILLIMETERS.
- 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
- DIMENSIONS D AND E DO NOT INLCUDE MOLD PROTRUSION.
- 4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE. 5. DIMENSION B DOES NOT INCLUDE DAMBAR
- 5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS					
DIM	MIN	MAX				
Α	2.35	2.65				
A1	0.10	0.25				
В	0.35	0.49				
С	0.23	0.32				
D	10.15	10.45				
Е	7.40	7.60				
е	1.27	BSC				
Н	10.05	10.55				
h	0.25	0.75				
L	0.50	0.90				
q	0 °	7 °				

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